SN74LVT240A **3.3-V ABT OCTAL BUFFER/DRIVER** WITH 3-STATE OUTPL

SCBS134K - SEPTEMBER 1992 - REVISED JANUARY 2004

•	Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V	DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)
•	V _{CC}) Supports Unregulated Battery Operation	10E [1 20] V _{CC} 1A1 2 19 20E
•	Down To 2.7 V Typical V _{OLP} (Output Ground Bounce)	2Y4 3 18 1Y1
•	<0.8 V at V _{CC} = 3.3 V, T _A = 25°C	1A2 4 17 2A4 2Y3 5 16 1Y2
•	I _{off} and Power-Up 3-State Support Hot Insertion	1A3 [] 6 15 [] 2A3 2Y2 [] 7 14 [] 1Y3
•	Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II	1A4 [] 8 13]] 2A2 2Y1 [] 9 12 [] 1Y4
•	ESD Protection Exceeds JESD 22 – 2000-V Human-Body Model (A114-A)	GND [10 11] 2A1

- 200-V Machine Model (A115-A)
- 1000-V Charged-Device Model (C101)

description/ordering information

This octal buffer and line driver is designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The SN74LVT240A is organized as two 4-bit buffer/line drivers with separate output-enable $\overline{(OE)}$ inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

TA	PACKA	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	Tube		SN74LVT240ADW	11/70 404	
	SOIC – DW	Tape and reel	SN74LVT240ADWR	LVT240A	
	SOP – NS	Tape and reel	Tape and reel SN74LVT240ANSR		
–40°C to 85°C	SSOP – DB	Tape and reel	SN74LVT240ADBR	LX240A	
	TOOOD DW	Tube	SN74LVT240APW	1.20404	
	TSSOP – PW	Tape and reel	SN74LVT240APWR	LX240A	
	TVSOP – DGV	Tape and reel	SN74LVT240ADGVR	LX240A	

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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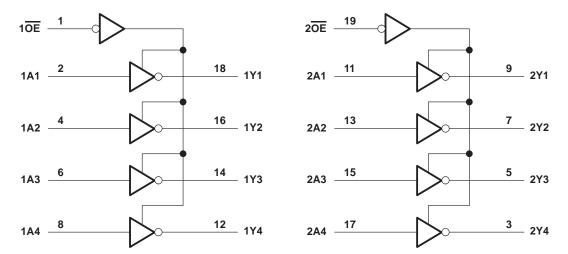
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FUNCTION TABLE (each 4-bit buffer)									
INP	UTS	OUTPUT							
OE	Α	Y							
L	Н	L							
L	L	Н							
Н	Х	Z							

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in the high-		
or power-off state, V _O (see Note 1)		
Voltage range applied to any output in the high	state, V _O (see Note 1)	–0.5 V to V _{CC} + 0.5 V
Current into any output in the low state, IO		128 mA
Current into any output in the high state, IO (see	e Note 2)	64 mA
Input clamp current, I _{IK} (V _I < 0)		
Output clamp current, I_{OK} (V _O < 0)		
Package thermal impedance, θ_{IA} (see Note 3):	DB package	
	DGV package	
		58°C/W
		60°C/W
Storage temperature range, T _{stg}		

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This current flows only when the output is in the high state and $V_O > V_{CC}$.

3. The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
VCC	Supply voltage		2.7	3.6	V
VIH	High-level input voltage		2		V
VIL	Low-level input voltage			0.8	V
VI	Input voltage			5.5	V
ЮН	High-level output current			-32	mA
IOL	Low-level output current			64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		200		μs/V
Т _А	Operating free-air temperature		-40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	V _{CC} = 2.7 V,	I _I = -18 mA				-1.2	V
	V _{CC} = 2.7 V to 3.6 V,	I _{OH} = -100 μA	I _{OH} = -100 μA				
VOH	V _{CC} = 2.7 V,	I _{OH} = – 8 mA	I _{OH} = – 8 mA				V
	V _{CC} = 3 V,	I _{OH} = -32 mA		2			
		I _{OL} = 100 μA				0.2	
	$V_{CC} = 2.7 V$	I _{OL} = 24 mA				0.5	
VOL		I _{OL} = 16 mA				0.4	V
	$V_{CC} = 3 V$	I _{OL} = 32 mA				0.5	
		I _{OL} = 64 mA	I _{OL} = 64 mA			0.55	
	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10		
1.	V _{CC} = 3.6 V	$V_I = V_{CC}$ or GND	Control inputs			±1	۸
1 ₁		VI = VCC	Data inputs	1			μA
		V _I = 0				-5	
l _{off}	$V_{CC} = 0,$	V_{I} or V_{O} = 0 to 4.5 V				±100	μA
IOZH	V _{CC} = 3.6 V,	V _O = 3 V				5	μA
IOZL	V _{CC} = 3.6 V,	V _O = 0.5 V				-5	μA
IOZPU	$V_{CC} = 0$ to 1.5 V,	V_{O} = 0.5 V to 3 V,	OE = don't care			±100	μΑ
IOZPD	V _{CC} = 1.5 V to 0,	V_{O} = 0.5 V to 3 V,	OE = don't care			±100	μA
			Outputs high			0.19	
ICC	$V_{CC} = 3.6 V,$ $V_{I} = V_{CC} \text{ or GND}$	l _O = 0,	Outputs low			5	mA
			Outputs disabled			0.19	
ΔI_{CC}^{\ddagger}	$V_{CC} = 3 V \text{ to } 3.6 V, \text{One}$	input at V _{CC} – 0.6 V, Othe			0.2	mA	
Ci	V _I = 3 V or 0			4		pF	
Co	$V_{O} = 3 V \text{ or } 0$			7		pF	

[†] All typical values are at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$.

[‡]This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.



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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

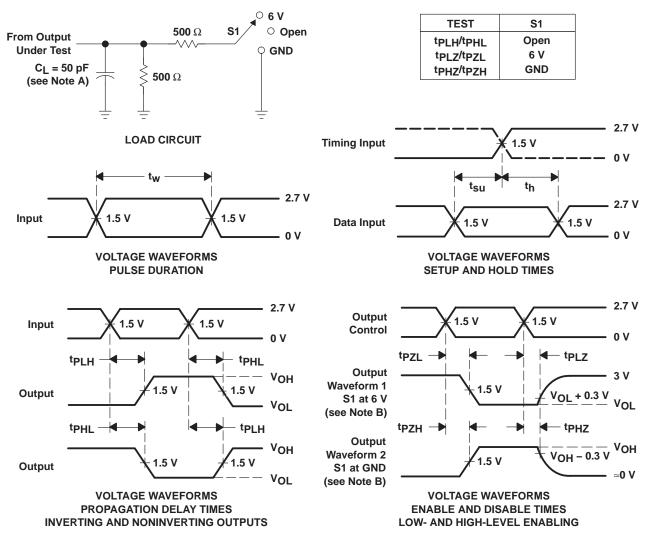
PARAMETER	FROM	TO	۷c	CC = 3.3 ± 0.3 V	V	V _{CC} =	2.7 V	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP†	MAX	MIN	MAX	
^t PLH	٨				3.8		4.6	
^t PHL	A	T	1.3	2.6	4		4.2	ns
^t PZH	OE	v		2.6	4.6		5.6	
^t PZL	ÛE	Y	1.4	2.7	4.4		5	ns
^t PHZ	OE	V	2	2.9	4.4		4.6	
^t PLZ	ÛE	Ŷ	1.8	3	4.3		4.3	ns

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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11-Nov-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVT240ADBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ADWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ANSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ANSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240ANSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT240APWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and



package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

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TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVT240ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVT240ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LVT240ANSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LVT240APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVT240ADBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVT240ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVT240ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVT240APWR	TSSOP	PW	20	2000	367.0	367.0	38.0

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

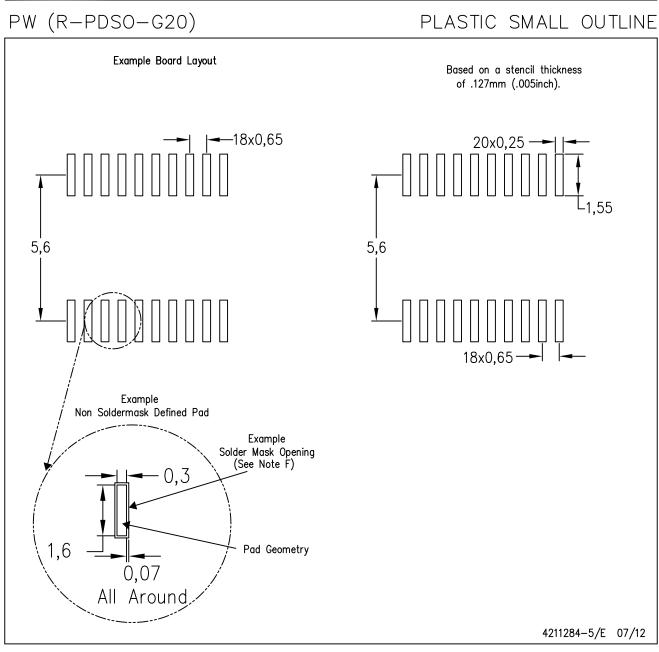
Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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